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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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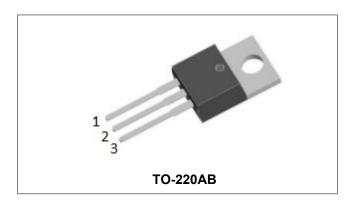








# **MBR4030CT SCHOTTKY RECTIFIER**



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

# **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-		
Working Peak Reverse Voltage	$V_{RWM}$		30	V
DC Blocking Voltage	$V_R$			
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=118°C, rectangular wave form	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	300	A

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	$V_{F1}$	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.48	0.55	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.1	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R, T_J = 125  ^{\circ}\text{C}$	80	110	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	960	1140	pF
Series Inductance(Per Leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

<sup>•</sup> China - Germany - Korea - Singapore - United States •

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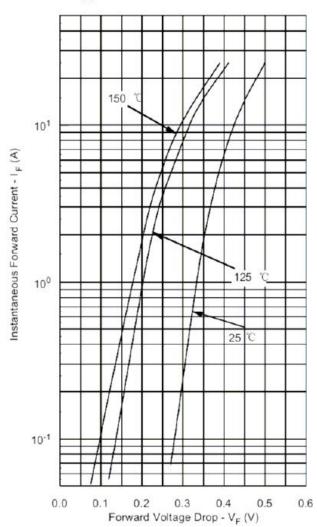


# **Thermal-Mechanical Specifications:**

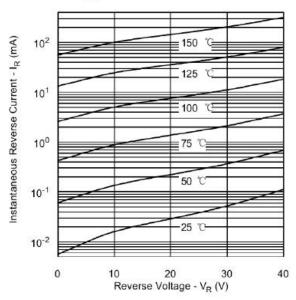
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	3.25	°C/W
Typical Thermal	R <sub>θ</sub> JS	Mounting surface, smooth and	0.5	°C/W
Resistance, Case to Heat Sink		greased		
Approximate Weight	wt	-	2	g

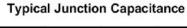
# **Ratings and Characteristics Curves**

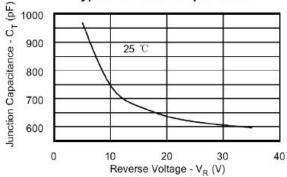
### Typical Forward Characteristics



### **Typical Reverse Characteristics**







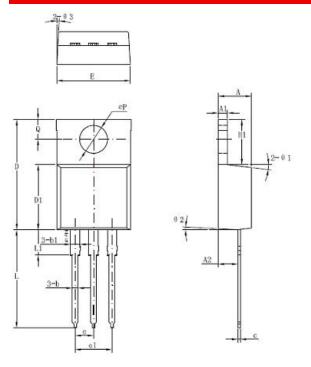
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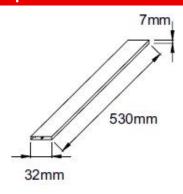


#### **Mechanical Dimensions TO-220AB**



Symbol		Dimensions in millimeters			
	Min	Typical	Max		
Α	4.42	4.57	4.72		
A1	1.17	1.27	1.37		
A2	2.52	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
D	14.94	15.24	15.54		
D1	8.85	9.00	9.15		
E	10.01	10.16	10.31		
е		2.54			
e1	4.98	5.06	5.18		
H1	6.04	6.24	6.44		
L	12.7	13.56	13.80		
L1	3.56	3.5	3.96		
ФР	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		7°			
Θ2		3°			
Θ3		4°			

# **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

 MBR
 = Device Type

 40
 = Forward Current (40A)

 30
 = Reverse Voltage(30V)

 CT
 = Configuration

 SSG
 = SSG

 YY
 = Year

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
MBR4030CT	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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